Synthesis of Taylor and Bayliss Patterns for Linear Antenna Arrays

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	The history of synthesis techniques for				
	terns is reviewed briefly, and the limitations				
small arrays are pointed out. Taylor's continuous aperture synthesis procedure is outlined, and a technique for transforming it for application to a discrete array is described. Discrete-array design					
	equations for Taylor and Bayliss synthesis procedures are given. A set of programs for use on a				
	programmable calculator are presented.				

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# SYNTHESIS OF TAYLOR AND BAYLISS PATTERNS FOR LINEAR ANTENNA ARRAYS

#### INTRODUCTION

The requirement for low sidelobes from array-type antennas is a long-standing one. The contributions to this theory extend from Dolph's utilization of Chebyshev polynomials, through Taylor's papers on linear and circular apertures, Bayliss's extension to difference-type patterns, and finally to recently developed techniques which provide arbitrary pattern control for linear arrays [1-8].

The purpose of this report is to examine some of the more recent applications of these synthesis techniques in light of their limitations and also the computational capabilities which are now available. For example, at the time Taylor published his synthesis procedure, engineers had only slide rules, mathematical tables, and mechanical desk calculators to generate the distribution functions. The computational capability available to today's engineer is vastly different, and we will show how Taylor's and Bayliss's procedures can be modified to give better results.

A more careful look at the synthesis procedures previously mentoned is presented in Table 1.

Dolph's synthesis is precise and gives minimum beamwidth for given sidelobe levels, but these constant amplitude sidelobes are not desirable for larger arrays because it is possible to radiate most of the energy into the sidelobes. Taylor solved this problem by allowing the far-out sidelobes to fall off as dictated by an amplitude discontinuity at the ends of the aperture. Taylor, and later Bayliss, synthesized continuous distributions and sampled these to obtain array excitations.

Table 1 — Synthesis Procedures for Linear Array Apertures

Procedure/ Date	Continuous or Discrete	Limitations
Dolph/47	Discrete	Poor results for large arrays
Taylor/52	Continuous	Inexact for low sidelobes, small arrays
Bayliss/68	Continuous	Inexact for low sidelobes, small arrays
Hyneman/68	Continuous	Inexact for low sidelobes, small arrays—iterative
Stutzman/72	Continuous	Inexact for low sidelobes, small arrays—iterative
Elliott/76	Continuous	Inexact for low sidelobes, small arrays—iterative
Elliott/77	Discrete	Applies all continuous procedures to discrete arrays

Manuscript submitted June 15, 1981.

Some recent applications have called for lower sidelobes and smaller arrays, thereby pressing the limitations of the Taylor and Bayliss synthesis procedures. The problem of discretizing continuous aperture distributions has been treated [9-10]. The technique used in this report is different from those of Winter and of Elliott, but it is mathematically related to Elliot's technique.

#### REVIEW OF TAYLOR SYNTHESIS PROCEDURE

A brief review of the Taylor synthesis procedure is given here. The key to this procedure is the equal-sidelobe pattern function which is the continuous-aperture analog to the Chebyshev polynomial pattern for arrays:

$$E(u) = \cos \pi \sqrt{u^2 - A^2},\tag{1}$$

where  $u = \pi a \sin \theta / \lambda$ , a is the length of the aperture and  $\theta$  is the angle measured relative to the normal to the array. This function has a maximum value of  $\cosh \pi A$  at u = 0 and unit sidelobes extending to  $u = \pm \infty$ . Taylor showed that the pattern of Eq. (1) is not physically realizable from a continuous aperture distribution, just as the Dolph array excitation becomes increasingly impractical in the limit of large arrays. His brilliant solution to this problem was:

1. For all zeros of the synthesized pattern functions, which we will call  $E_s(u)$ , from the *n*th from the origin to  $\infty$ , the locations will be the same as those from a uniformly illuminated aperture of the same size. That is,

$$E_s(u) = 0$$
 for  $u = n$  for  $n \ge \overline{n}$ .

2. For the first  $\overline{n} - 1$  zeros, their locations will be determined by the zeros of E(u), scaled so that the nth zero is located at  $u = \overline{n}$ .

The aperture distribution is determined by performing a Woodward synthesis of  $E_s(u)$ . That is, we define a set of functions of the form

$$F_n(u) = \sin (u - n)\pi/(u - n)\pi,$$

and then construct  $E_s(u)$  from the  $F_n(u)$ 

$$E_s(u) = \sum_{n = -\infty}^{\infty} E_s(n) F_n(u).$$
 (2)

Since we have defined  $E_s(n) = 0$  for  $n \ge \overline{n}$ , Eq. (3) becomes

$$E_s(u) = \sum_{n=-\bar{n}+1}^{\bar{n}-1} E_s(n) F_n(u). \tag{3}$$

Fourier transformation of Eq. (3) yields the aperture distribution:

$$A(x) = \int_{-\infty}^{\infty} E_s(u) e^{j2xu\pi/a} du$$

$$= \int_{-\infty}^{\infty} \sum_{n=-n+1}^{\overline{n}-1} E_s(n) F_n(u) e^{j2xu\pi/a} du.$$
(4)

That is, A(x) is a weighted sum of integrals of the form,

$$\int_{-\infty}^{\infty} \frac{\sin (u-n)\pi}{(u-n)\pi} e^{j2xu\pi/a} du.$$

Letting u' = u - n results in

$$e^{j2n\pi x/a}\int_{-\infty}^{\infty}\frac{\sin u'\pi}{u'\pi} e^{j2xu'\pi/a}du'.$$

Since the imaginary part of the integrand is odd, this becomes

$$e^{j2n\pi x/a} \int_{-\infty}^{\infty} \frac{\sin u'\pi \cos 2xu'\pi/a \ du'}{u'\pi}$$

$$= e^{j2n\pi x/a} \int_{-\infty}^{\infty} \frac{1}{2} \left[ \frac{\sin u'\pi (1 - 2x/a) + \sin u'\pi (1 + 2x/a)}{u'\pi} \right] \ du'. \tag{5}$$

A standard definite integral is

$$\int_{-\infty}^{\infty} \frac{\sin bz dz}{z} = \pi \text{ for } b > 0$$

$$= 0 \text{ for } b = 0$$

$$= -\pi \text{ for } b < 0$$

Application of this integral to Eq. (5) and thence to Eq. (4) yields

$$A(x) = \sum_{n=-\overline{n}+1}^{\overline{n}-1} E_s(n)e^{j2\pi nx/a}$$

$$= E_s(0) + 2 \sum_{n=1}^{\overline{n}-1} E_s(n) \cos 2\pi nx/a \text{ for } |x| \le a/2$$

$$= 0 \qquad \text{for } |x| > a/2.$$
(6)

The continuous aperture distribution given by Eq. (6) is sampled to give the element excitation values for a discrete array. This last step is approximate, and the pattern function of the array is obviously different from  $E_s(u)$ . This approximation is acceptable provided that the number of elements in the array is much greater than  $\overline{n}$  and the sidelobe level is not extremely low. Figure 1 is an example of a case in which the synthesis procedure gives an unsatisfactory result. For a sidelobe level of 50 dB below mainbeam and  $\overline{n} = 8$ , a 30-element array has the computed pattern function shown. The near-in sidelobes are unduly low, whereas the first eight sidelobes should be about the same level.

#### ARRAY PATTERN FUNCTIONS IN TERMS OF ZEROS

Elliott used a synthesis technique which relates the discrete array distribution directly with the array pattern [9]. We also use this relationship, and our procedure achieves identical results with those of Elliott. However, the actual computations are different, and it is desirable to compare the techniques.

Elliott expresses the pattern function as a polynomial in w, where  $w=e^{j(2\pi s/\lambda)\sin\theta}$ . The zeros of this polynomial are given by  $w_n$ , which are normally located on the unit circle. Once he has the  $w_n$  properly adjusted, he completes the synthesis by multiplying out the product expression,  $\Pi(w-w_n)$ , into the polynomial. The coefficients of the polynomial are the excitations of the array elements.

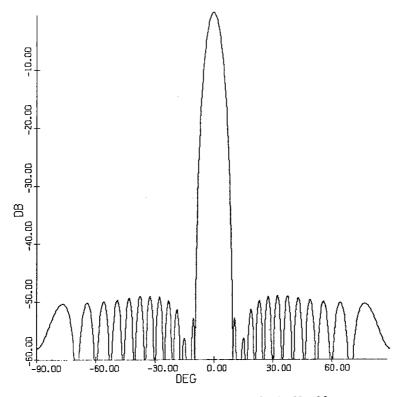


Fig. 1 — Conventional Taylor synthesis, N = 30,  $\bar{n} = 8$ , 50-dB sidelobes

Our procedure also uses the pattern function zeros in a product expression. Since the patterns are symmetric, our expression can be of the form,  $\Pi(\cos z - \cos z_n)$ , where  $z = (2\pi s/\lambda) \sin \theta$ . We cannot multiply this product expression out to obtain the coefficients directly since we require terms of the form  $\cos nz$  rather than  $\cos^n z$ . Rather, we carry out a synthesis exactly analogous to that used by Taylor. Uniformly spaced pattern function samples are found by using the product expression. These pattern samples are used in a Fourier series to find the array illumination.

The procedure relies on the equivalent location of pattern function zeros for the line source and for the discrete array. Whereas the zeros for the pattern of a uniform line source distribution are located at u = n, the analogous relationship for a discrete array is  $z = n\pi/N$ , where  $z = 2\pi s \sin \theta/\lambda$ , where s is element spacing and N is the number of elements in the uniformly excited array.

The transformation of Taylor's procedure is easily seen to consist of locating the zeros in step 1 above at  $z = n\pi/N$  for  $n \ge \overline{n}$  and then scaling the first  $\overline{n}$  zeros of Eq. (1) so that the  $\overline{n}$ th zero is located at  $z = \overline{n}\pi/N$ .

Appendix A lists the resulting equations for Taylor arrays of both even and odd N, and Appendix B lists the equations for Bayliss arrays (yielding monopulse difference patterns) of both even and odd N. Figure 2 is an example of a Taylor array pattern with sidelobe levels of 50 dB with  $\overline{n}=8$  and N=30. These equations can be straightforwardly programmed for automatic processing by a digital computer. Many programmable calculators now have sufficient memory to implement these programs. Appendix C lists programs for carrying out the synthesis and evaluating the pattern functions with an HP-41C programmable calculator.

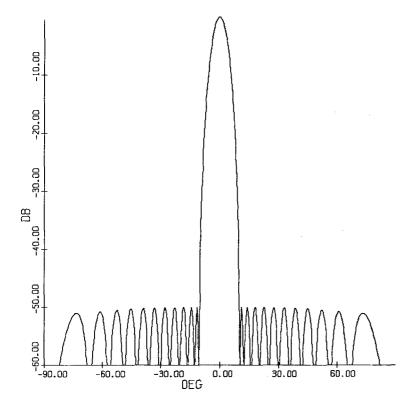


Fig. 2 — Discretized Taylor synthesis,  $N = 30, \bar{n} = 8, 50$ -dB sidelobes

#### ACKNOWLEDGMENT

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#### Appendix A

# DESIGN EQUATIONS FOR LINEAR ARRAYS WITH TAYLOR-TYPE PATTERNS

These equations will determine the aperture illumination coefficients for a linear array of N elements to produce a Taylor-type pattern function with  $\overline{n}$  sidelobes on each side of the main beam at a level of L dB.

This design procedure involves three steps. The first  $\overline{n} - 1$  zeros of the pattern are determined. Then the appropriate pattern function samples are determined. Finally, the array element illumination coefficients are determined by a harmonic analysis of the pattern function samples.

A particular advantage of this synthesis is that the knowledge of all of the pattern function zeros allows the computation of the pattern function as a product rather than as a polynomial. The product computation involves only one trigonometric function evaluation for each pattern function value. All other constants need to be evaluated only once for each array.

The pattern function zeros are given by

$$z_n = \frac{2\pi \overline{n} \sqrt{A^2 + (n - 1/2)^2}}{N\sqrt{A^2 + (\overline{n} - 1/2)^2}} \quad \text{for } n = 1 \text{ to } \overline{n} - 1$$
 (A1a)

$$=\frac{2\pi n}{N} \qquad \text{for } n = \overline{n} \text{ to } M, \qquad (A1b)$$

where

$$M = \operatorname{int}\left(\frac{N-1}{2}\right)$$

and A is given by

$$A = \frac{1}{\pi} \cosh^{-1} \left[ 10^{(L/20)} \right]$$
 (A2a)

$$\approx (L + 6.02)/27.29$$
, (A2b)

where L is the sidelobe level (positive) in dB. Equation (A2b) is an excellent approximation, especially for large L.

The pattern function is given by

$$E(z) = \cos \frac{z}{2} \prod_{n=1}^{M} \left( \frac{\cos z - \cos z_n}{1 - \cos z_n} \right) \qquad N \text{ even}$$

$$= \prod_{n=1}^{M} \left( \frac{\cos z - \cos z_n}{1 - \cos z_n} \right) \qquad N \text{ odd}$$
(A3)

The pattern samples to be used to find the array element illumination coefficients are given by

$$a_m = E\left(\frac{2\pi m}{N}\right)$$
 for  $m = 1$  to  $\overline{n} - 1$ . (A4)

The element excitation coefficients are given by

$$\begin{split} e_p &= 1 + 2 \sum_{m=1}^{\overline{n}-1} a_m \cos \frac{m(2p-1)\pi}{N} & N \text{ even, } p = 1 \text{ to } M + 1 \\ &= 1 + 2 \sum_{m=1}^{\overline{n}-1} a_m \cos \frac{2mp\pi}{N} & N \text{ odd, } p = 0 \text{ to } M \text{ ,} \end{split} \tag{A5}$$

where p is an index or element number starting at the center and moving to either end of the array.

#### Appendix B

### DESIGN EQUATIONS FOR LINEAR ARRAYS WITH BAYLISS-TYPE DIFFERENCE PATTERNS

Appendix A gave the design equations for linear arrays with Taylor-type patterns, which produce a main beam with slightly larger beamwidth than that of the Dolph synthesis but in general with higher gain. In some applications; such as monopulse, we might require a difference pattern. Bayliss presented a synthesis procedure for difference patterns, analogous to that of Taylor. In this appendix we adapt the Bayliss procedure to discrete arrays.

As in the case of the Taylor synthesis, the application of discrete arrays involves three steps. The first  $\overline{n} - 1$  off-axis zeros of the pattern are determined. Then the appropriate pattern function samples are determined. Finally the array element illumination coefficients are determined by a harmonic analysis of the pattern function samples.

The pattern function zeros are given by

$$z_n = \frac{2\pi q_n \left(\overline{n} + \frac{1}{2}\right)}{N\sqrt{A^2 + \overline{n}^2}}$$
 for  $n = 1, 2, 3, 4$  (B1a)

$$= \frac{2\pi\left(\overline{n} + \frac{1}{2}\right)\sqrt{A^2 + n^2}}{N\sqrt{A^2 + \overline{n}^2}} \quad \text{for } n = 5 \text{ to } \overline{n} - 1$$
 (B1b)

$$= \frac{2\pi\left(n + \frac{1}{2}\right)}{N} \qquad \text{for } n = \overline{n} \text{ to } M$$
 (B1c)

where

$$M=\operatorname{int}\left(\frac{N-2}{2}\right).$$

In this case it is necessary to find both A and  $q_n$  from graphs in Bayliss's paper [4]. For 50 dB sidelobes,  $A=2.42,\ q_1=2.78,\ q_2=3.18,\ q_3=3.85,\ \text{and}\ q_4=4.65.$ 

The pattern function is given by

$$E(z) = \sin\frac{z}{2} \prod_{n=1}^{M} \left[ \cos z - \cos z_n \right] / \sin\frac{z_1}{4} \prod_{n=1}^{M} \left[ \cos\frac{z_1}{2} - \cos z_n \right] \qquad N \text{ even}$$
 (B2)

$$= \sin z \prod_{n=1}^{M} \left[ \cos z - \cos z_n \right] / \sin \frac{z_1}{2} \prod_{n=1}^{M} \left[ \cos \frac{z_1}{2} - \cos z_n \right] \qquad N \text{ odd}$$

E(z) is normalized to unity at  $z = z_1/3$ , which is near the pattern maximum. If a more precise pattern maximum is desired, a better multiplying constant can easily be found.

The pattern samples to be used to find the array element illumination coefficients are given by

$$b_m = E\left(\frac{\pi}{N}(2m-1)\right) \quad \text{for } m = 1 \text{ to } \overline{n} . \tag{B3}$$

The element excitation coefficients are given by

$$e_p = 2 \sum_{m=1}^{\overline{n}} b_m \sin \frac{\pi (2m-1)(2p-1)}{2N} \quad \text{for } N \text{ even, } p = 1 \text{ to } M+1$$

$$= 2 \sum_{m=1}^{\overline{n}} b_m \sin \frac{\pi (2m-1)p}{N} \quad \text{for } N \text{ odd, } p = 1 \text{ to } M+1 \quad (B4)$$

where p is an index of the element number starting with zero at the center of the array. For N odd, the center element of the array always has zero excitation. The excitations on one side of the array are the negative of those on the other side.

#### Appendix C

#### PROGRAMS FOR THE HP-41C CALCULATOR

This appendix presents programs for the HP-41C calculator for the design equations of Appendices A and B. The software consists of four programs, SUM, DIF, IN, and SL. "SUM" contains the equations for synthesizing Taylor-type sum patterns; "DIF" contains equations for Bayliss-type difference patterns; "IN" contains subroutines that are used by both programs; and "SL" is a routine for calculating the peaks of the sidelobes of the synthesized array. The number of registers used by the programs and the number of card sides required for storage are:

Program	Registers	Card Sides
SUM	30	2
$\operatorname{DIF}$	42	3
IN	39	3
$\operatorname{SL}$	19	_2
	130	10 (5 cards).

It is possible to synthesize aperture distributions using either SUM and IN or DIF and IN. These programs require at least one additional memory module. Furthermore, the programs use nine registers for variables, indices, and constants. Table C1 correlates the number of registers available for synthesis parameters with the number of additional memory modules in use. The available registers are used for the pattern samples  $a_m$  and  $b_m$  and for the pattern function zeros (cosines)  $z_p$ . The number of these registers is  $\overline{n}+M$ . Therefore, the size of array that can be synthesized for any given configuration of Table C1 depends on  $\overline{n}$ . For a 50-dB sidelobe requirement,  $\overline{n}$  will be about 8. Roughly speaking, an array of 55 to 65 elements for difference and 80 to 90 for sum can be synthesized using one memory module by trading programs in and out of the machine, and an array of 90 to 100 elements can be synthesized with all programs loaded using two modules. The maximum array size that can be handled using three modules is 310 to 320 for difference and about 340 for sum. It appears that one or two memory modules should suffice for most requirements.

Table C1 — Registers Available after Loading Indicated Program Complements

Program Complement	Number of Memory Modules			
Program Complement	1	2	3	
SUM + IN DIF + IN SUM + DIF + IN SUM + DIF + IN + SL	48 35 11 —	112 99 71 54	176 163 135 118	

The procedure for running the programs is:

- 1. Allocate memory by XEQ SIZE (9 + M + n).
- 2. Load the appropriate program complement.
- 3. Enter either XEQ SUM or XEQ DIF.
- 4. The display will prompt for N, L, and NBAR. N can be even or odd. L is sidelobe level in positive dB. DIF will also prompt for A, Q1, Q2, Q3, Q4.
- 5. After calculating  $z_n$  and loading  $\cos z_n$  into registers starting with  $(9 + \overline{n})$ , the display will ask whether you want a listing of peak sidelobes (SL) or aperture distribution (EP). After the sidelobes or excitation coefficients are listed, the display will ask whether you want the other set of parameters calculated and listed.

The routine SL computes the sidelobe level relative to the main beam level by evaluating the pattern value at a point midway between pattern zeros. This computation is admittedly approximate because the pattern maximum is in general not exactly midway between zeros. The main beam pattern value is computed for z = 0. The difference pattern maximum is computed for  $z = z_1/3$ . This factor was found to be accurate for 50 dB sidelobes. The exact multiplying factor will be somewhat larger for higher sidelobes (L < 50), and it can be found quickly by obtaining  $z_1$  and executing PA:

```
RCL (9 + \overline{n}) gives \cos z_1 ACOS gives z_1 he mew multiplying factor, such as .4 * COS STO 02 XEQ PA .
```

Alternatively, k can be found from Fig. 4 of Bayliss^{C1}, which defines the beam maximum by  $p_o$ , where  $k = p_o / \S_1$ . ( $\S_1$  corresponds to our  $z_1$ )

Once the desired value of k has been found, go to lines 110, 111 in DIF, and exchange k, * for 3,/. It is now necessary to reload the reference main beam pattern value into R08. This calculation starts at line 61 of SUM and 105 of DIF. Alternatively, you can simply rerun the program.

The pattern value, in voltage and normalized to mainbeam level, is found by keying in the value of z in degrees, then keying COS, STO 02, XEQ PA.

The registers used are:

PA
nts

C1 E. T. Bayliss, BSTJ, May-Jun 1968, pp. 623-650.

07	accumulator for $E(z)$ , $e_p$
08	main beam reference value
09 to $(8 + \bar{n})$	computed values of $a_m$ , $b_m$
$(9+\overline{n})$ to $(8+\overline{n}+M)$	computed values of $\cos z_n$ .

#### Program IN contains the following subroutines:

IN	Asks for input data $N, L, NBAR$
ZN	Completes calculation and storage of $\cos z_n$
BR	Asks for choice of sidelobes or aperture distribution and branches
	to EP or SL
PR	Prints element excitations $e_n$
PA	Computes pattern value for $a_m$ , $b_m$ , or SL routines
EP	Completes calculation of $e_n$ .

The programs use flags 00 and 01 to indicate the following conditions:

Flag 00 is set for N even clear for N odd

Flag 01 is set for DIF execution clear for SUM execution.

The use of registers by program PA precludes the use of the plot subroutines resident in the printer.

Note that the sidelobes and pattern values obtained with these programs are all relative to the main beam level. No information concerning gain or aperture illumination efficiency is computed. The aperture distribution can be used to compute aperture efficiency or gain.

The programs and sample printouts are listed on the following pages.

45 KCL 61 46 1 E-5 47 * 64 59 STO 64 517 360 52 RCL 68 54 STO 66	92 OF 61 93 XER "IN" 94 RCL 98 97 C 1 11 350 12 RCL 98 15 X 2 16 RCL 98 17 .5 18 - 5 18 - 6 18 - 7 19 Xf2 20 RCL 93 21 + RCL 93 22 SQRT 23 X 20 26 L 63 27 - 6 28 FCL 93 28 RCL 93 28 RCL 93 29 RCL 93 27 - 6 28 RCL 93 28 RCL 93 27 - 7 28 RCL 93 28 RCL 93 29 RCL 93 27 - 7 28 RCL 93 28 RCL 93 29 RCL 93 20 RCL 94 41 SQRT 42 XEQ "ZN" 43 ISC 94 44 SQRT 45 SQRT 46 SQRT 47 SQRT 48 SQRT 49 SQRT 40 SQRT 41 SQRT 42 XEQ "ZN"	r Or-
98 STO 66 99 ( 100 f 101 FC? 80 102 G 103 FC? 80 104 C 105 RCL 81 106 + 107 ( E-3	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	55+  6  62
13 F1X 6 14 ARCL X 15 FRA 16 X*72 17 STO 60 18 360 19 RCL 66 20 / 21 RCL 66 22 RCL 60	189 + 111 *LBL 64 111 *LBL 64 112 RTL 63 114 1 115 - 115 RTL 63 114 1 115 - 115 RTL 63 115 RTL 63 116 RTL 63 117 * 118 RTL 63 119 STC 65 128 FC 670 65 128 RTL 67 129	
68 1 68 1 69 - 78 X/Y? 71 GTO 16 72 1 E-3 73 + 74 + 75 STO 84	24 + 27	23 842

w	128 /			52 PROMPT
76+1.3L 08	129 STO 06	ei+LBL "IN"		
77 ROL 62	127 0.0 00	62 FIX 0		53 A=0?
78 RCL 04	4 70 L ( P) - 4 2	03 CF 00		54 RIN
79 INT	130+LSL 14	04 "N="		55 GTO "SL"
80 X12	131 RCL 05	05 PROMPT		
81 +	132 IMT	06 ARCI X	*	56*LBL "PR"
	133-2		*	57 "E"
<b>8</b> 2 SØRT	134 *	67 PEH -	•	58 RCL 04
83 XE0 .5%	135 1	08 STO 00		
84 /SG 04		<b>69</b> 2		59 INT
65 GTO 08	136	10 /		60 FIX 0
	137 RCL 06	11 ENTERT		61 ARCL X
86+LBL 10	138 *	12 FRC		62 ACA
87 360	139 COS			63 FIX 4
	140 STO 02	13 X=0?		64 "="
88 RCL 00	141 XEQ "PA"	14 SF 00	1.8. 1.	65 ACA
891/	142 RCL 05	i5 "L='	11.5	
90 STO 06		16 PROMPT	•	66 RDN
91 RCL 03	143-8	17 ARCL X		67 ACX
92 RCL 01	14+ +	18 PRA		68 PRBUF
	145 XCXY			69 ISG 04
93 1 E-3	146 STO IND Y	19 26	fir .	70 RTN
94 *	147 ISG 05	20 /		
35 t	148 GTO 14	21 2	•	71 AD√
96 STO 04		22 LQG		72 "SL? 0"
	149 RCL 01	23 +		73 PROMPT
97+LBL 11	150 1	2411		74 X=0?
98 RCL 04	15i +			75 GTO "SL"
	152 1 E-3	25 EtX		76 STOP
99 INT	153 *	26 LOG		10 010
100.5	154 1	27 PI		99.15: #86:
101 +		28 *	v sil Solak ida 131 bas	77+LBL "PA"
102 XEQ "ZN"	155 +	29 /	1 1 1	78 RCL 01
103 ISG 04	i56 STO 04	30 Xt2		79 1 E-3
104 GTJ 11	157 96	31 STO 02	**	86 *
105 RCL 03	158 RCL 00	32 "NBAR="	1	81 1
	159 /			82 +
106 9	160 STO 06	33 PROMPT		83 STO 04
107 +	100 010 00	34 ARCL X		
108 RCL IND R	42444 0 45	35 PRA		84 1
109 ACOS	.161+LBL 15	<b>3</b> 6 STO 03		85 STO 07
119 3	162 i	-37 RTK		
111 /	163 RCL <b>0</b> 3	VI 1511		86+LBL 00
	164 1 E-3	704.51 6755		87 RCL 04
112 003	165 *	38+LBL "ZN	**	88 RCL 03
113 STO 02	166 +	39 RCL 06	.* .	89 +
1:4 1	167 STC 05	40 *		
115 STO 08	168 Ø	41 COS	:	98 8
116 XEQ "PA"		43 RCL 03		91 +
117 STO 08	169 370 M7	43 %		92 RCL 02
118 XEQ "BR"		44 +		93 RCL IND Y
"to ura so	170∗L8L 16	45 RCL 64		94 -
. 46 -2 51 - 65 6	171 XE0 "EF"			95 \$1* 97
119*LBL "0"	172 186 05	46 +		96 ISG 04
120 RCL 03	173 GTO 16	47 X<>Y		
12i 1 E-3	174 2	48 STO IND		97 GTO 00
122 *		49 RTN		98 1
125 t	175 RCL 87	•		99 FS7 <b>0</b> 0
124 +	176 *	50+LBL "BR"		100 GTO 01
125 STO 05	177 XEQ "FR"	51 "SL? 1/EP? 0"		101 FC7 01
	178 GTO 15	Of Other Materials		102 GTO 03
126 180	179 STOP			103 RCL 02
127 RCL 00	180 END			The Law Am
	15			

104 ACOS		151+LBL 85	*
104 ACOS 105 SIN 106 GTO 03		152 RCL 05	
106 GTO 03		153 8 154 +	
		155 8 154 + 155 XC>Y 156 RCL IND Y 157 *	40 180
107+LBL 01		155 XCXV	41 RCL 00
108 RCL 02	•	156 ROL IND 9	42 /
109 ACOS		157 * 158 ST+ 07 159 RTN 160 END	43 STO 06
110 2		150 CT± A7	
111 /		159 RTN 160 END	44+LEL 0)
112 FS? 0i		160 END	45 (
113 GTO 02		200 CMD	46 FS? 0)
114 COS			47 8
115 GTO 03			48 RCL 05
		PRP "SL"	49 INT
116+LBL 02	•	FRY GE	50 2
117 SIN	*	9i+LBL "SL"	51 🛊
		AS *C! DEAKS TO:	52 +
118+LBL 03		01+LBL "SL" 02 "SL PEAKS, DE" 03 PRA 04 FIX 2	53 RCL 0h
119 ROL 07		SA CIV A	54 *
120 *		64 F1X Z	55 COS
121 RCL 08		05 1 06 RCL 03	56 STG 02
122 /		00 KUL 83	57 XEQ 03
123 RTN		Ø/ (	58 ISG 05
TLO RIN		68 -	59 GTO 61
124+181 "EP"		87 I E-3	69 ADV
125 -1		10 → 11	61 STOP
124+LBL "EP" 125 -1 126 FC? 00 127 0		07 ( 08 - 09 1 E-3 10 * 11 + 12 STO 05	
127 0		12 3.0 60	62+LBL 03
128 RCL 04		13+LBL 00	63 STO 02
129 INT		14 RCL 63	64 XEQ "PA
130 2		15 8	<b>65 AB</b> S
i3i *		16 +	66 LOG
132 +		17 RCL 05	67 20
133 RCL 05		18 +	68 *
134 INT		18 + 19 RCL IND X 20 ACOS	69 CHS
135 2		20 ACOS	70 PRX
136 *	• •	21 X()Y	71 RTN
137 FC? 81		22 1	72 "EP? 0"
138 GTO 03	.*	23 +	73 PROMPT
139 [		24 X()Y	74 X≠0?
140 -		25 RCL IND Y	75 STOP
		26 ACOS	76 FS? 01
141+LBL 03		27 +	77 GTO *0*
142 *		28 2	78 GTO "S"
143 RCL 06	•	29 /	79 END
144 *		<b>36</b> COS	
145 F37 01		31 XED 83	
146 GTO 04		32 ISG 05	
147 COS	;	33 GTO 00	
148 GTO <b>9</b> 5	* .	34 RCL 03	
MONTH DE		35 RCL 61	
149+LBL 04		36 1 E-3	
150 SIN		37 *	
		38 +	
		39 STO 05	

```
M=21
N=20
 L=50
L=50
 MBAR=8
NBAR=8
 E6= 1,9579
Ei= 1.9452
 E1= 1.9111
E2= 1.8439
 E2= 1.7766
E3= 1.6549
 E3= 1.5702
E4= 1.4021
 E4= 1.3156
E5= 1.1166
 E5= 1.0403
E6= 0.8294
 E6= 0.7766
E7= 0.5684
 E7= 0.5291
E8= 0.3527
 E8= 0.3306
E9= 0.1903
 E9= 0.1812
E10= 0.0965
 E10= 0.0957
SL PEAKS, DB
 SL PEAKS, DB
 本本字
 50.33
 50.35
 49.93
 本本字
 49.95
 老字子
 49.82
 车字本
 49.86

 49.72
 本字本
 49.77
 本本年
 45.60
 本字字
 49.67
 塞津先
 49,45

 49.56

 49.29
 非常本
 49.43
 本水子
 49.09
 水水率
 49.26

 49.09
 未字字
 49.29

 49.31
N=20
 N=21
 L=50
 L=58
 NBAR=8
 NBAR=8
 A=2.42
 H=2.42
 Q1 = 2.78
 Q1= 2.78
 Q2= 3.18
 92= 3.18
 Q3= 3.85
 03= 3.85
 Q4= 4.65
 Q4= 4.65
 E1= 0.4886
 £1= 0.9093
 E2= 1.3673
 E2= 1.6548
 E3= 1.9831
 E3= 2.1187
 E4= 2.2448
 E4= 2.2516
 E5= 2.1556
 E5= 2.0835
 E6= 1.8001
 E6= 1.7813
 E7= 1.3679
 E7= 1.2231
 E8= 0.8180
 E8= 0.7650
 E9= 0.4184
 E9= 0.3953
 E10= 0.1751
 510= 0.1726
 SL PEAKS, DB
 SL PEAKS, DB
 49.54
 本共本
 本字本
 49.56
 本字字
 48.41
 事字库
 48.44
 47.91
 单淬车
 水本米
 47.94
 非常无
 46,89
 水井市
 46.53
 47.09
 中华军
 未来来
 47.15
 46.96

 塞塞木
 46.98
 46.55
 本本字

 46.64
 未本年
 46.56
 本本方
 46.65
 45.64
 本半年
 45.93
```

